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# M54HC221 M74HC221

# DUAL MONOSTABLE MULTIVIBRATORS

- HIGH SPEED tpp = 32 ns (TYP) at V<sub>CC</sub> = 5V
- LOW POWER DISSIPATION STANDBY STATE  $I_{CC} = 4 \ \mu A$  (MAX.) at  $T_A = 25^{\circ}C$ ACTIVE STATE  $I_{CC} = 200 \ \mu A$  (TYP) at  $V_{CC} = 5V$
- HIGH NOISE IMMUNITY  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (MIN.)
- OUTPUT DRIVE CAPABILITY 10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE |I<sub>OH</sub>| = I<sub>OL</sub> = 4 mA (MIN.)
- BALANCED PROPAGATION DELAYS tPLH = tPHL
- WIDE OUTPUT PULSE WIDTH RANGE twout = 150ns ~ 60s over at V<sub>CC</sub> = 4.5V
- PIN AND FUNCTION COMPATIBLE WITH 54/74LS221

# DESCRIPTION

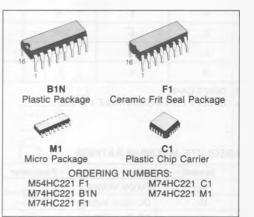
The M54/74HC221 is a high speed CMOS MONO-STABLE multivibrator fabricated with silicon gate C<sup>2</sup>MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation. There are two trigger inputs, A INPUT (negative edge) and 8 INPUT (positive edge). These inputs are valid for rising/falling signals, (t<sub>r</sub>t<sub>r</sub>l sec).

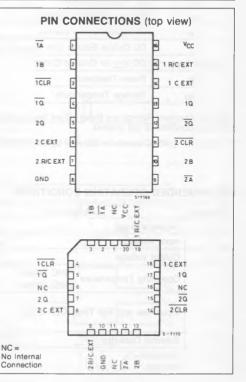
The device may also be triggered by using the CLR input (positive-edge) because of the Schmitt-trigger input; after triggering the output maintains the MO-NOSTABLE state for the time period determined by the external resistor Rx and capacitor Cx. Taking CLR low breaks this MONOSTABLE STATE. If the next trigger pulse occurs during the MONO-STABLE period it makes the MONOSTABLE period longer. Limit for values of Cx and Rx:

Cx : NO LIMIT

 $\begin{array}{rl} \text{Rx} & : & \text{V}_{\text{CC}} = & 2.0 \text{V} & 5 \text{K} \Omega & \text{to} & 1 \text{M} \Omega \\ \text{V}_{\text{CC}} = & 3.0 \text{V} & 1 \text{K} \Omega & \text{to} & 1 \text{M} \Omega \end{array}$ 

All inputs are equipped with protection circuits against static discharge and transient excess voltage





October 1988

# **TRUTH TABLE**

NOTE	UTS	OUTP	INPUTS				
NOTE	Q	Q	CLR	В	Ā		
OUTPUT ENABLE	J	<u> </u>	н	н	-		
INHIBIT	HA	LA	н	L	X		
INHIBIT	H▲	LA	н	х	н		
OUTPUT ENABLE	J		н		L		
OUTPUT ENABLE	T	L	_	н	L		
INHIBIT	Н	L	L	х	х		

X: DON'T CARE

▲: EXCEPT FOR MONOSTABLE PERIOD

## **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	-0.5 to 7	V
Vi	DC Input Voltage	- 0.5 to V <sub>CC</sub> + 0.5	V
Vo	DC Output Voltage	- 0.5 to V <sub>CC</sub> + 0.5	V
IIK	DC Input Diode Current	± 20	mA
IOK	DC Output Diode Current	± 20	mA
IO	DC Output Source Sink Current Per Output Pin	± 25	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current	± 50	mA
PD	Power Dissipation	500 (*)	mW
Tstg	Storage Temperature	- 65 to 150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

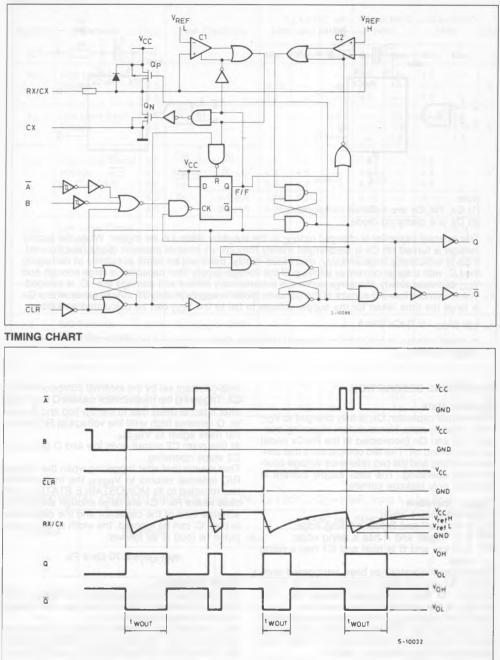
(\*) 500 mW:  $\cong$  65°C derate to 300 mW by 10 mW/°C: 65°C to 85°C

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Unit	
V <sub>CC</sub>	Supply Voltage	2 to 6	5	V
Vi	Input Voltage	0 to V <sub>C</sub>	c	V
Vo	Output Voltage	0 to V <sub>C</sub>	c	V
TA	Operating Temperature 74HC Series 54HC Series	- 40 to - 55 to	°C	
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (CLR only)	V <sub>CC</sub> 4.5V	0 to 1000 0 to 500 0 to 400	ns
Сх	External Capacitor	NO LIMITA	NO LIMITATION	
Rx	External Resistor	Voc (	5K to 1M 1K to 1M	Ω

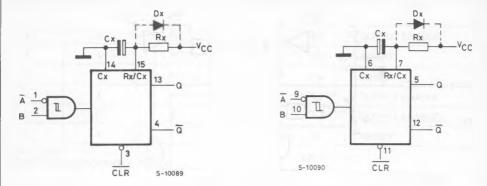
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# LOGIC DIAGRAM





### **BLOCK DIAGRAM**



#### Note:

(1) Cx, Rx, Dx are external components.(2) Dx is a clamping diode

The external capacitor is charged to V<sub>CC</sub> in the stand-by state, i.e. no trigger. When the supply voltage is turned off Cx is discharged mainly through an internal parasitic diode (see figures). If Cx is sufficiently large and V<sub>CC</sub> decreases rapidy, there will be some possibility of damaging the I.C. with a surge current or latch-up. If the voltage supply filter capacitor is large enough and V<sub>CC</sub> decreases slowly, the surge current is automatically limited and damage the I.C. is avoided. The maximum forward current of the parasitic diode is approximately 20 mA. In cases where Cx is large the time taken for the supply voltage to fall to 0.4 V<sub>CC</sub> can be calculated as follows:

 $t_f \ge (V_{CC} - 0.7) \cdot Cx/20mA$ 

In cases where  $t_f$  is too short an external clamping diode is required to protect the I.C. from the surge current.

### FUNCTIONAL DESCRIPTION

#### Stand-by state

The external capacitor, Cx, is fully charged to  $V_{CC}$  in the stand-by state. Hence, before triggering, transistor Qp and Qn (connected to the Rx/Cx node) are both turned off. The two comparators that control the timing and the two reference voltage sources stop operating. The total supply current is therefore only leakage current.

#### **Trigger operation**

Triggering occurs when:

- 1<sup>st</sup>) A is "low" and B has a falling edge;
- 2<sup>nd</sup>) B is "high" and A has a rising edge;
- 3<sup>rd</sup>) A is low and B is high and C1 has a rising edge.

After the multivibrator has been retriggered comparator C1 and C2 start operating and Qn is turned on. Cx then discharges through Qn. The voltage at the node Rx/Cx external falls.

When it reaches  $V_{\text{REFL}}$  the output of comparator C1 becomes low. This in turn resets the flip-flop and Qn is turned off. At this point C1 stops functioning but C2 continues to operate.

The voltage at R/C external begins to rise with a

time constant set by the external components Rx, Cx. Triggering the multivibrator causes Q to go high after internal delay due to the flip-flop and the gate. Q remains high until the voltage at R/C external rises again to  $V_{\text{REFH}}$ .

At this point C2 output goes low and O goes low. C2 stops operating.

That means that after triggering when the voltage R/C external returns to  $V_{REFH}$  the multivibrator has returned to its MONOSTABLE STATE. In the case where Rx • Cx are large enough and the discharge time of the capacitor and the delay time in the I.C. can be ignored, the width of the output pulse tw (out) is as follows:

$$t_{W(OUT)} = 0.70 \text{ Cx} \cdot \text{Rx}$$

#### **Reset Operation**

CL is normally high. If CL is low, the trigger is not effective because Q output goes low and trigger control flip-flop is reset.

Also transistor Qp is turned on and Cx is charged quickly to  $V_{CC}$ . This means if CL input goes low, the IC becomes waiting state both in operating and non operating state.



# DC SPECIFICATIONS

Symbol	Parameter	Vcc	V <sub>CC</sub> Test Condition			T <sub>A</sub> = 25°C 54HC and 74HC		- 40 to 85°C 74HC		– 55 to 125°C 54HC		Unit
					Min. Typ	Тур.	Max.	Min.	Max.	Min.	Max.	
V <sub>IH</sub>	High Level Input Voltage	2.0 4.5 6.0			1.5 3.15 4.2	-	_	1.5 3.15 4.2	-	1.5 3.15 4.2	-	v
VIL	Low Level Input Voltage	2.0 4.5 6.0					0.5 1.35 1.8	-	0.5 1.35 1.8		0.5 1.35 1.8	v
V <sub>OH</sub>	High Level Output Voltage (Q, Q Output)	2.0 4.5 6.0 4.5 6.0	V <sub>IN</sub> V <sub>IH</sub> or V <sub>IL</sub>	l <sub>0</sub> - 20 μA - 4.0 mA - 5.2 mA	1.9 4.4 5.9 4.18 5.68	2.0 4.5 6.0 4.31	111	1.9 4.4 5.9 4.13	111	1.9 4.4 5.9 4.10	1 1 6	v
V <sub>OL</sub>	Low Level Output Voltage (Q, Q Output)	2.0 4.5 6.0 4.5 6.0	V <sub>IH</sub> or V <sub>IL</sub>	- 5.2 mA 20 μA 4.0 mA 5.2 mA	5.08	5.8 0 0 0.17 0.18	0.1 0.1 0.1 0.26 0.26	5.63 — — — —	0.1 0.1 0.1 0.33 0.33	5.60	0.1 0.1 0.1 0.40 0.40	v
lj -	Input Leakage Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND		-	-	±0.1	-	±1	_	±1	μA
li	R/C Terminal Off-State Current	6.0	V <sub>I</sub> = V	V <sub>I</sub> = V <sub>CC</sub> or GND		_	±0.5	_	±5	-	± 10	μA
lcc	Quiescent Supply Current	6.0	V <sub>i</sub> = V	CC or GND	-	_	4	-	40	-	80	μA
lcc'	Active-State (1) Supply Current	2.0 4.5 6.0		$V_{CC}$ t = 0.5 V <sub>CC</sub>	-	40 0.1 0.2	120 0.3 0.6		160 0.4 0.8	_	200 0.5 1.0	μA mA mA

(1): Per Circuit

# AC ELECTRICAL CHARACTERISTICS ( $V_{CC} = 5V$ , $T_A = 25^{\circ}C$ , $C_L = 15pF$ , Input $t_r = t_f = 6ns$ )

		54HC and 74HC						
Symbol	Parameter Min.		Тур.	Max.	Unit			
t <sub>TLH</sub> t <sub>THL</sub>	Output Transition Time		4	8	ns			
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Time (Ā, B TRIGGER - Q, Q)		32	49	ns			
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Time (CLR TRIGGER - Q, Q)		35	55	ns			
tPLH tPHL	Propagation Delay Time (CLR - Q, Q)		23	37	ns			



# M54/74HC221

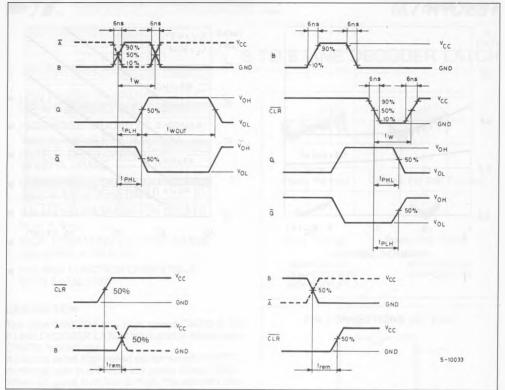
# **AC ELECTRICAL CHARACTERISTICS** ( $C_L = 50pF$ , Input $t_r = t_f = 6ns$ )

Symbol	Parameter	Parameter V <sub>CC</sub> Test Condition 54		т 54Н0	T <sub>A</sub> = 25°C 54HC and 74HC			o 85°C HC	– 55 to 125°C 54HC		Unit
				Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
t <sub>TLH</sub> T <sub>THL</sub>	Output Transition Time	2.0 4.5 6.0		-	30 8 7	75 15 13		95 19 16	-	110 22 19	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Time (Ā,B TRIG Q,Q)	2.0 4.5 6.0			144 36 31	280 56 48		350 70 60		420 84 71	ns
tpLH tpHL	Propagation Delay Time (CLR TRIG Q,Q)	2.0 4.5 6.0		-	164 41 35	310 62 53		390 78 66	-	465 95 79	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Time (CLR - Q,Q)	2.0 4.5 6.0	-		108 27 23	210 42 36		265 53 45		315 63 54	ns
<sup>t</sup> W(H) t <sub>W</sub> (L)	Minimum Trigger Pulse Width	2.0 4.5 6.0		-	30 8 7	75 15 13		95 19 16	-	110 22 19	ns
tw(L)	Minimum Clear Pulse Width	2.0 4.5 6.0			30 8 7	75 15 13	-	95 19 16	-	110 22 19	ns
∆tw(out)	Output Pulse Width Error. Between Circuits in Same Package			Ĵ	±1		-	-	-	-	%
<sup>t</sup> REM	Minimum Removal Time (Ā,B TRIGGER)	2.0 4.5 6.0		-		0 0 0	-	0 0 0		0 0 0	ns
<sup>t</sup> REM	Minimum Removal Time (CLR TRIGGER)	2.0 4.5 6.0			_	0 0 0		0 0 0		0 0 0	ns
<sup>t</sup> wout (Min).	Minimum Output Pulse Width	2.0 4.5 6.0	$\label{eq:cx} \begin{split} & Cx = OpF \\ & Rx = 5kpF\Omega(V_{CC} = 2V) \\ & Rx = 1k\Omega(V_{CC} = 4.5,6V) \end{split}$		490 190 170	1450 290 260		1825 365 325	-	2185 437 373	ns
twout	Output Pulse Width	2.0 4.5 6.0	$Cx = 0.01 \mu F$ $Rx = 10 k\Omega$	72 72 72	85 80 80	98 88 88	72 72 72	98 88 88	72 72 72	98 88 88	μS
		2.0 4.5 6.0	$Cx = 0.1 \mu F$ Rx = 10k $\Omega$	0.67 0.67 0.67	0.75 0.73 0.73	0.83 0.79 0.79	0.67 0.67 0.67	0.83 0.79 0.79	0.67 0.67 0.67	0.83 0.79 0.79	ms
CIN	Input Capacitance			_	5	10	_	10	_	10	рF
C <sub>PD</sub> (*)	Power Dissipation Capacitance			_	109	-	_	_	-	_	pF

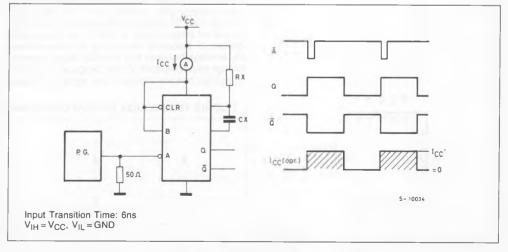
Note (\*)  $C_{PD}$  is defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load (refer to Test circuit). Average operating current can be obtained by equation hereunder:  $I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC'} \cdot Duty/100 + I_{CC}/2$  (per monostable) ( $I_{CC'}$ : Active Supply Current, Duty: %)



# SWITCHING CHARACTERISTICS TEST WAVEFORM

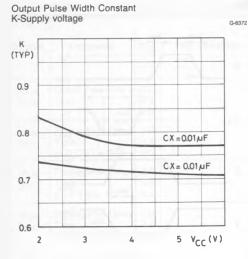


## **TEST WAVEFORM**

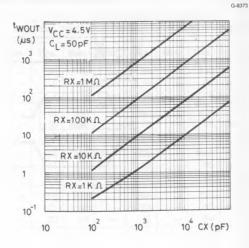


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twOUT-Cx Characteristics (Typ).



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